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Effect of Gd doping and O deficiency on the Curie temperature of EuO

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Abstract

The effect of Gd doping and O deficiency on the electronic structure, exchange interaction, and Curie temperature of EuO in the cubic and tetragonal phases is studied by means of density functional theory. For both defects, the Curie temperature is found to exhibit a distinct maximum as a function of the defect concentration. The existence of optimal defect concentrations is explained by the interplay of the on-site, RKKY, and superexchange contributions to the magnetism.

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I. INTRODUCTION

In recent years europium monoxide, EuO, has received considerable attention as a potential material for spintronics, because of its special electronic and magnetic properties. The compound has a rock salt structure, and it is a ferromagnetic insulator below the Curie temperature of $T_C = 69$ K.[1,2] The divalent Eu ions possess a large magnetic moment of 7 μ_B, originating from the half-filled $4f$ states, which are separated by an energy gap of 1.12 eV from the Eu $5d$ conduction band.[3] EuO is suitable as spin filter due to its spin polarization of almost 100%, as demonstrated both by experiment[2,4–6] and theory.[7] Spin filter tunneling junctions (metal/EuO/metal heterojunctions) based on polycrystalline EuO have been studied in various experiments.[8–14] Integration of EuO on semiconducting GaAs,[15] GaN,[5] and Si[5,16] has been demonstrated. Particularly, the possibility of growth on graphene[17] and topological insulators[18] is interesting for spintronics devices.

The ferromagnetism of EuO, in general, originates from indirect exchange, J_1, and superexchange, J_2. It is widely accepted that the indirect exchange is governed by the Eu $4f$ and $5d$ orbitals,[19,20] whereas the superexchange involves the hybridized Eu $4f$ and O $2p$ orbitals,[21] where mediation by $6s$ and $5d$ states appears to be important.[22,23] It has been suggested by Ingle and Elfimov[19] that T_C can be enhanced most effectively by reducing the gap between the Eu $4f$ and $5d$ states, and by minimizing the hybridization between the Eu $4f$ and O $2p$ states. In this context, rare earth doping with La, Lu, and Gd, has been studied experimentally,[24–34] by model approaches,[1,35–37] and by first-principles calculations.[19–21,29,31,38–40] The effects of rare earth doping, which is efficient only for low dopant concentrations, have been explained by modifications of the on-site and RKKY interactions.[20] On the other hand, enhancement of T_C can also be achieved in O deficient EuO,[41–43] and by the application of tensile strain.[23] In fact, epitaxial growth of EuO on appropriate substrates can result in a tetragonal or an orthorhombic structure.[34]

Commonly used methods for modeling doping effects on the electronic structure of EuO are the virtual crystal approximation[29,38] and the rigid band approximation.[31] First-principles calculations for Gd-doped EuO by the supercell approach (partial substitution of Eu by Gd) have been reported in Ref. 39 without addressing the exchange interaction. Insight into the magnetism has been accomplished in Refs. 20 and 40 for a restricted set of configurations.

In contrast, the purpose of our work is to investigate the effect of Gd doping and O deficiency in the entire concentration range relevant for experiment, focusing on the electronic structure, exchange interaction, and T_C. We will start by introducing our methodology in Sect. II, then analyze first the effect of Gd doping (Sect. III), and afterwards (Sect. IV) that of O deficiency. The conclusions are given in Sect. V.

II. METHODS

In our first-principles calculations we use a linear combination of atomic orbitals and Troullier-Martins norm-conserving relativistic pseudopotentials (as implemented in the SIESTA code).[44] The wave functions are expanded in a ζ+polarization basis, except for the Eu $4f$ states for which we use a single-ζ basis. A cutoff of 600 Ry is employed together with $4 \times 4 \times 4$ and $6 \times 6 \times 4$ uniform meshes, respectively, for sampling the Brillouin zones of the cubic and tetragonal phases. To achieve an accurate description of the EuO band gap, we use the local density approximation with on-site Coulomb repulsions ($U's$), and exchange parameters ($J's$).[45,46] Note that these parameters refer to the microscopic interacting-electron problem; in particular, these $J's$ should not be confused with the exchange interactions of the effective Heisenberg model, to be discussed at the end of this section.

For the Eu $4f$ states we set $J_f = 0.77$ eV,[19] but we vary U_f between 8 and 9 eV since the band structure depends critically on the on-site potential of the Eu $4f$ states. A value of $U_f = 8.8$ eV gives the best agreement with the experimental situation (band gap of 1.1 eV, and band splitting of 0.6 eV).[2,4] Following Ref. 19 we use $J_p = 1.2$ eV and $U_p = 4.6$ eV for the O $2p$ orbitals. Moreover, for the Gd $4f$ orbitals we set $J_f = 0.7$ eV and $U_f = 6.7$ eV.[47,48]

The experimental lattice constant of 5.144 Å is used for the rocksalt structure (cubic phase), with four Eu and four O atoms per unit cell. For the tetragonal phase we start from the lattice parameters $a = 3.65$ Å (inter-planar spacing) and $c = 5.12$ Å (out-of-plane spacing). For both phases, $2 \times 2 \times 2$ supercells are built, which are shown in Fig. 1. These supercells are fully relaxed by means of the conjugate gradient method until the atomic forces have declined below 0.01 eV/Å. We obtain for the cubic phase $a = 5.097$ Å and for the tetragonal phase $a = 3.635$ Å and $c = 5.080$ Å. These values are kept fixed when building the respective structures under Gd doping and O deficiency. Under this constraint,

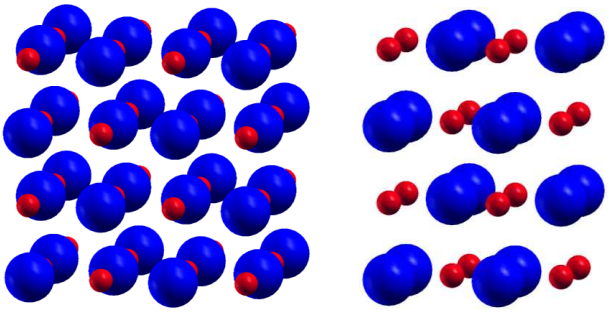


FIG. 1. (Color online) Structure of EuO in the cubic phase (left) and the tetragonal phase (right). Large spheres (blue) represent Eu, small spheres (red) represent O. The front side is the xz-plane.

we have carefully relaxed all atomic positions which, of course, is mandatory in order to be able to obtain reliable results. Gd concentrations between 6.25% and 25% are considered, by substituting Eu atoms by Gd; O vacancy concentrations in the same range are achieved by removing O atoms from the supercell.

The nearest neighbor (NN, J_1) and next-nearest neighbor (NNN, J_2) exchange interactions for the cubic phase are determined by fixing three spin configurations, and calculating their respective energies: the ferromagnetic one (FM), an antiferromagnetic (AFM) one with the spin direction alternating in the (001) direction (AFM1), and an AFM one with the spin direction changing every second layer in the (001) direction (AFM2). The total energies (per cation) are related to the J_1 and J_2 as follows:[49]

$$\begin{aligned} E_{\mathrm{FM}} &= E_0 + S(S+1)(-12J_1 - 6J_2), \\ E_{\mathrm{AFM1}} &= E_0 + S(S+1)(4J_1 - 6J_2), \\ E_{\mathrm{AFM2}} &= E_0 + S(S+1)(-4J_1 - 2J_2) \end{aligned} \tag{1}$$

where $S = 7/2$. Given J_1 and J_2, an effective Heisenberg model can be defined; and similarly for the tetragonal case (next paragraph).

For the tetragonal phase ($c > a$), we have in-plane NN ($J_{1\parallel}$), out-of-plane NN ($J_{1\perp}$), in-plane NNN ($J_{2\parallel}$), and out-of-plane NNN ($J_{2\perp}$) interactions. Note that the term in-plane refers to the xy-plane of the tetragonal supercell, which is rotated by 45° with respect to the cubic supercell. To determine the exchange interactions in this case, we have to study five spin configurations: FM, AFM1, AFM2, AFM with the spin direction alternating in the (110) direction (AFM3), and AFM with the spin direction alternating every 2nd layer

in the (100) direction (AFM4). The total energies (per cation) are given by:

$$
\begin{aligned}
E_{\mathrm{FM}} &= E_0 + S(S+1)(-4J_{1\parallel} - 8J_{1\perp} - 4J_{2\parallel} - 2J_{2\perp}), \\
E_{\mathrm{AFM1}} &= E_0 + S(S+1)(-4J_{1\parallel} + 8J_{1\perp} - 4J_{2\parallel} - 2J_{2\perp}), \\
E_{\mathrm{AFM2}} &= E_0 + S(S+1)(-4J_{1\parallel} - 4J_{2\parallel} + 2J_{2\perp}), \\
E_{\mathrm{AFM3}} &= E_0 + S(S+1)(4J_{1\parallel} - 4J_{2\parallel} - 2J_{2\perp}), \\
E_{\mathrm{AFM4}} &= E_0 + S(S+1)(4J_{2\parallel} - 2J_{2\perp}).
\end{aligned}
\tag{2}
$$

In mean-field approximation this results in[19]

$$
\begin{aligned}
T_C^{\mathrm{cubic}} &= \frac{2}{3} S(S+1)(12J_1 + 6J_2), \\
T_C^{\mathrm{tetra}} &= \frac{2}{3} S(S+1)(4J_{1\parallel} + 8J_{1\perp} + 4J_{2\parallel} + 2J_{2\perp}).
\end{aligned}
\tag{3}
$$

III. GD DOPING

In order to clarify the effect of Gd doping for both the cubic and tetragonal phases we determine the density of states (DOS) projected on the Eu $4f$, $5d$, Gd $4f$, $5d$, and O $2p$ orbitals, see Fig. 2. The dependences of the different exchange terms and of T_C on the dopant concentration are addressed in Fig. 3. We first discuss the results for the pristine structures (0% doping), which are very similar for the cubic and tetragonal phases. For the majority spin channel we distinguish three regions: the conduction band (dominated by Eu $5d$ states), upper valence band (dominated by localized Eu $4f$ states, with some hybridization with O $2p$ and Eu $5d$), and lower valence band (dominated by O $2p$ states, with significant hybridization with Eu $4f$ and $5d$). The spin minority channel shows a similar structure but without the Eu $4f$ contributions. The energy gap between the valence and conduction bands amounts to 1.1 eV, and the exchange splitting of the Eu $5d$ states at the conduction band edge to 0.6 eV, in good agreement with the experiment.[4]

For the cubic phase, exchange interactions of $J_1 = 0.63$ K and $J_2 = 0.13$ K have been derived from single-crystal inelastic neutron scattering,[50] which by Eq. (3) corresponds to $T_C = 88$ K, while we find $J_1 = 0.50$ K and $J_2 = 0.26$ K and hence a T_C of 80 K, consistent with the experimental result. Note that our effective J ($= J_1 + J_2 = 0.76$ K) agrees with the experimental value. For the tetragonal phase, we obtain $J_{1\parallel} = 0.54$ K, $J_{2\parallel} = 0.19$ K, $J_{1\perp} = 0.49$ K, and $J_{2\perp} = 0.27$ K, from which a mean-field T_C of 77 K is calculated. However,

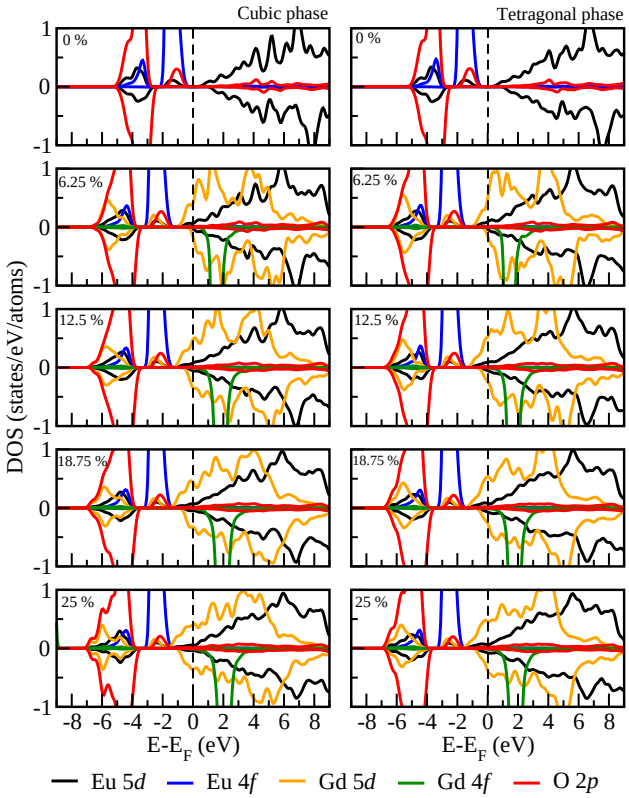


FIG. 2. DOS projected on the Eu $4f$, $5d$, Gd $4f$, $5d$, and O $2p$ orbitals for the cubic (left) and tetragonal (right) phases of EuO for different Gd concentrations

recent experiments on films of cubic and tetragonal EuO with 10 Å thickness have found critical temperatures of 56 K and 53 K, respectively.[34] While the absolute values deviate from our theoretical findings, we note that the difference between the two T_C's is exactly the same (3 K), This is a strong indication for the reliability of our calculations, as far as difference quantities and dependencies (like T_C vs. concentration) are concerned.

The effects of Gd doping on the DOS are similar for the cubic and tetragonal phases, see Fig. 2. The exchange splitting of the Eu $5d$ states at the conduction band edge essentially remains the same as in the pristine system. For increasing Gd doping, the Gd $5d$ and Eu $5d$ majority spin states shift to lower energy, increasing the system's metallicity. Since there are many more Gd $5d$ than Eu $5d$ conduction states occupied, mainly the Gd $5d$ states determine J_1 (combination of on-site and RKKY exchange). The hybridization between the Eu $4f$ and O $2p$ states decreases for increasing Gd doping, which reduces the value of J_2 (superexchange).

For 6.25% Gd doping the stronger exchange interaction between the Gd/Eu $5d$ and Eu $4f$

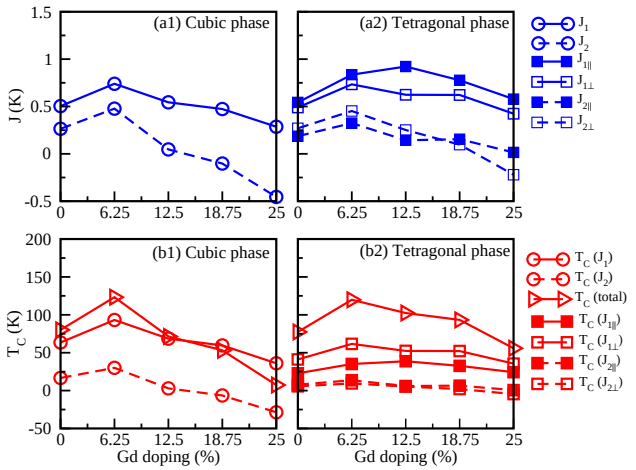


FIG. 3. Exchange interaction and corresponding T_C as a function of the Gd concentration for the cubic phase ((a1), (b1)), and the tetragonal phase ((a2), (b2))

states (the reduced energy gap supports the f-d hopping) in combination with the RKKY exchange mediated by the conduction states[20] enhances T_C to around 120 K, both in the cubic and tetragonal phases, see Fig. 3(b1),(b2), in good agreement with the experimental value of 129 K for 10% Gd doping.[26] In Ref. 20 a maximal T_C of 160 K for 10% Gd doping has been obtained on the basis of the virtual crystal approximation (using the parameters $J_f = 0.6$ eV and $U_f = 6.1$ eV for the Eu $4f$ states). While the validity of the virtual crystal approximation is difficult to assess in this context, we note that T_C depends strongly on the parameter U_f, which in our work was chosen to be $U_f = 8.8$ eV, in order to reproduce the experimental band gap. With increasing U_f, the band gap opens, hence T_C decreases, and vice versa.

Above 6.25% Gd doping we observe that the Gd/Eu $5d$ majority spin states shift further towards the Eu $4f$ states, which should enhance T_C. However, the minority spin states start getting filled and, as a consequence, the spin polarization at the Fermi energy is reduced. This compromises the RKKY interaction and therefore effectively lowers J_1 and T_C. In addition, an antiferromagnetic J_2 is observed for 18.75% and higher doping in both phases, which can be explained by enhanced hybridization between the Gd $5d$, Eu $5d$, and O $2p$ states: see, for example, the developing joint DOS peaks close to -5 eV.

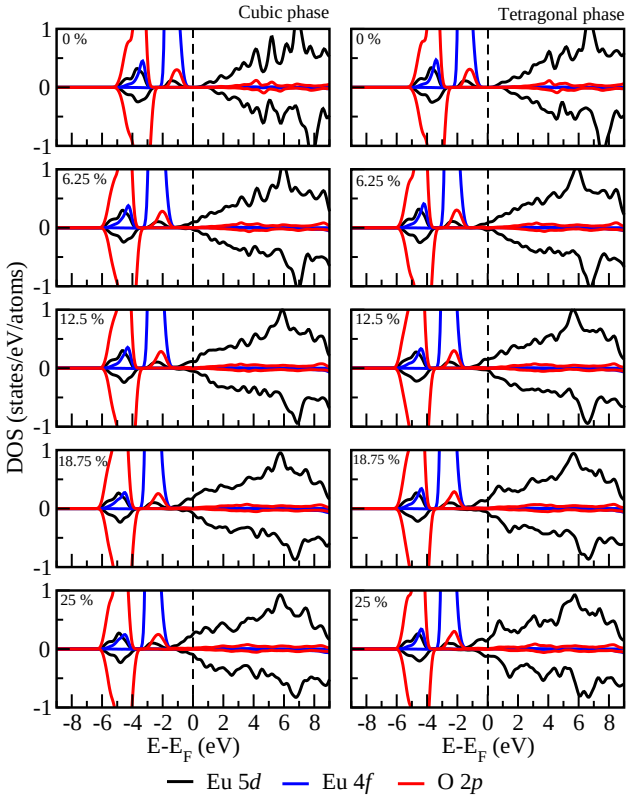


FIG. 4. DOS projected on the Eu $4f$, Eu $5d$, and O $2p$ orbitals for the cubic (left) and tetragonal (right) phases of EuO for different O vacancy concentrations

IV. O DEFICIENCY

We next analyze the effects of O deficiency by means of the DOS projected on the Eu $4f$, $5d$ and O $2p$ orbitals, see Fig. 4, for different O vacancy concentrations. In addition, Fig. 5 addresses the dependences of the different exchange terms and of T_C on the O vacancy concentration. As expected, O deficiency causes almost rigid shifts of all states to lower energy, so that more and more of the charge donated by the O vacancies occupies the Eu $5d$ conduction bands. It is generally accepted that positive effects on T_C due to O deficiency originate from this extra charge populating the conduction band, and giving rise to enhanced RKKY exchange,[1,23,41,42] which corresponds to an increase in J_1. However, also the gap between the majority spin Eu $5d$ and $4f$ states decreases substantially, and the f-d hopping is enhanced correspondingly, see Fig. 5(a1). The band structure (not shown) demonstrates that the exchange splitting of the Eu $5d$ states at the conduction band edge is reduced significantly for 6.25% O vacancy concentration, as compared to the pristine case,

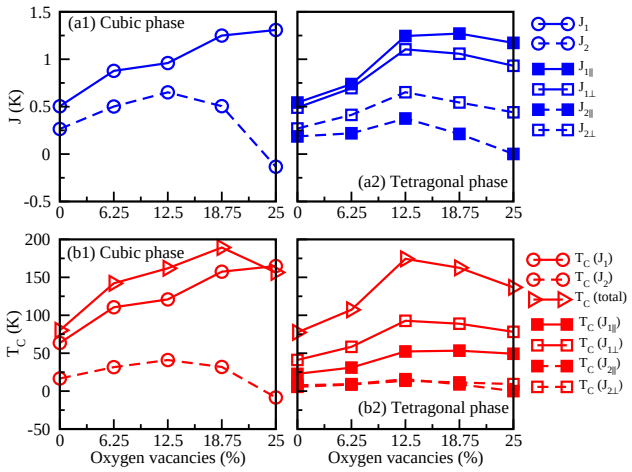


FIG. 5. Exchange interaction and corresponding T_C as a function of the O vacancy concentration for the cubic phase ((a1), (b1)) and the tetragonal phase ((a2), (b2))

and further slightly decreases for higher O vacancy concentrations.

In addition, the DOS demonstrates that hybridization between the Eu $4f$, $5d$ and O $2p$ states plays a significant role for the T_C value. We first focus on the cubic phase, see the left hand side of Fig. 4. Hybridization between the Eu $4f$ and O $2p$ states decreases as the O vacancy concentration increases, which enhances J_2, up to 12.5% O vacancy concentration. Afterwards J_2 declines rapidly. According to Fig. 5(b1), T_C increases, as J_1 increases, up to a maximum value of 190 K for 18.75% O vacancy concentration, and decreases thereafter, as J_2 decreases. The tetragonal phase, see the right hand side of Fig. 4, overall shows similar characteristics, i.e., $J_{1\|}$, $J_{1\perp}$, $J_{2\|}$, and $J_{2\perp}$, see Fig. 5(a2), first increase with O deficiency. However, now the Eu $5d$ minority spin states get filled for 12.5% and higher O vacancy concentrations, and J_1 is reduced accordingly, resulting in a maximum in T_C of about 175 K, see Fig. 5(b2).

V. CONCLUSION

We have performed first principles calculations for both Gd doped and O deficient EuO to clarify the mechanisms that determine the critical temperatures of the cubic and tetragonal phases. We extend previous theoretical considerations for the cubic phase to high defect concentrations, and present the first comprehensive account of the role of defects in the tetragonal phase. The calculated maximum in T_C, as a function of Gd concentration, is

in good agreement with the experimental value. The observed behavior is explained by a complex combination of different exchange mechanisms. While both the on-site and RKKY interactions increase with increasing (but low) doping, filling of the Gd $5d$ minority spin states at high doping counteracts the RKKY exchange. In addition, the superexchange is modified at high doping due to growing hybridization between the Gd $4f$ and O $2p$ states. The dependence of T_C on the O deficiency is controlled by a similar mechanism, though now the Eu $5d$ states take over the role of the Gd $5d$ states. As a consequence, optimal values exist both for the Gd dopant and O vacancy concentrations.

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